

SK32B - SK315B

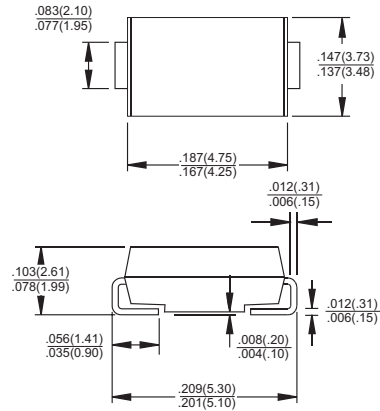
3.0 AMPS. Surface Mount Schottky Barrier Rectifiers

SMB/DO-214AA



Features

- ✧ For surface mounted application
- ✧ Metal to silicon rectifier, majority carrier conduction
- ✧ Low forward voltage drop
- ✧ Easy pick and place
- ✧ High surge current capability
- ✧ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ✧ Epitaxial construction
- ✧ High temperature soldering:
260°C / 10 seconds at terminals



Mechanical Data

- ✧ Case: Molded plastic
- ✧ Terminals: Pure tin plated, lead free.
- ✧ Polarity: Indicated by cathode band
- ✧ Packaging: 16mm tape per EIA STD RS-481
- ✧ Weight: 0.1 gram

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SK 32B	SK 33B	SK 34B	SK 35B	SK 36B	SK 39B	SK 310B	SK 315B	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	90	100	150	V
Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	63	70	105	V
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	90	100	150	V
Maximum Average Forward Rectified Current at T _L (See Fig. 1)	I _(AV)	3.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	70								A
Maximum Instantaneous Forward Voltage @ 3.0A	V _F	0.5			0.75		0.85		0.95	V
Maximum DC Reverse Current (Note 1) @ T _A =25 °C at Rated DC Blocking Voltage @ T _A =125 °C	I _R	0.5					0.1			mA
		10			5		2.0		mA	
Typical Thermal Resistance (Note 2)	R _{θJL}	17								°C/W
	R _{θJA}	75								
Operating Temperature Range	T _J	-55 to +125			-55 to +150					°C
Storage Temperature Range	T _{STG}	-55 to +150								°C

- Notes:
1. Pulse Test with PW=300 usec, 1% Duty Cycle
 2. Measured on P.C.Board with 0.4" x 0.4" (10mm x 10mm) Copper Pad Areas.

RATINGS AND CHARACTERISTIC CURVES (SK32B THRU SK315B)

FIG. 1- MAXIMUM FORWARD CURRENT DERATING CURVE

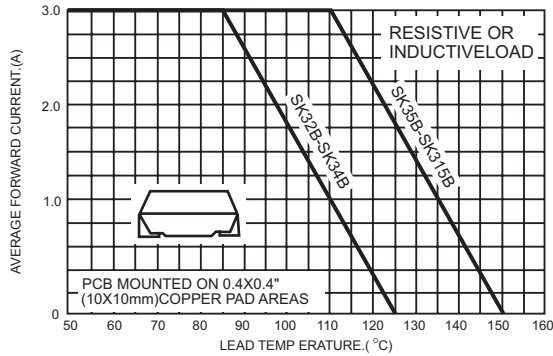


FIG. 2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

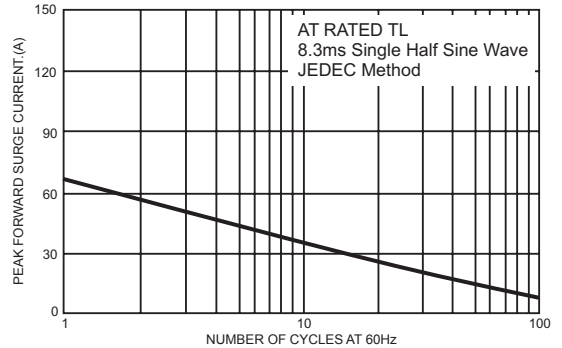


FIG. 3- TYPICAL FORWARD CHARACTERISTICS

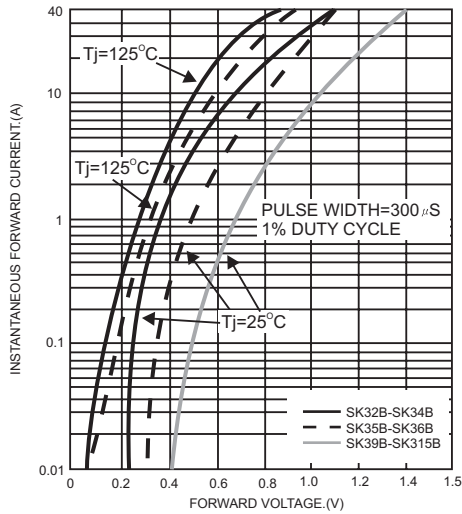


FIG. 4- TYPICAL REVERSE CHARACTERISTICS

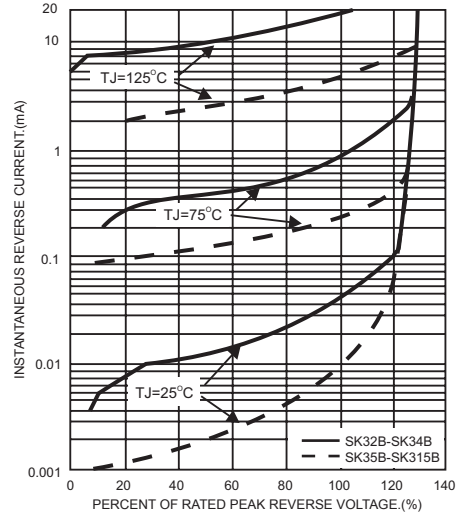


FIG. 5- TYPICAL JUNCTION CAPACITANCE

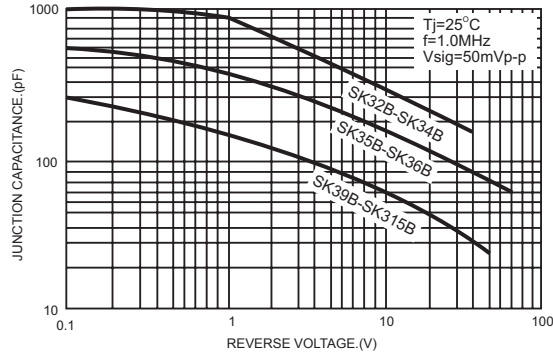
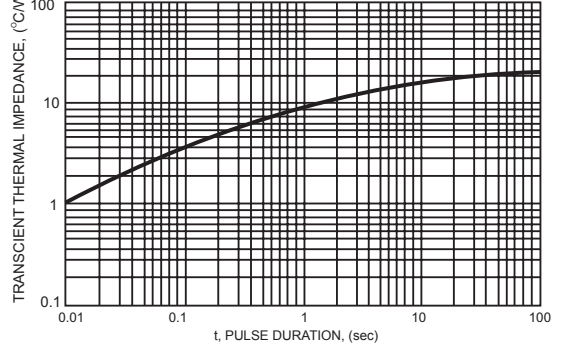


FIG. 6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS



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